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.M6317 120 MHz, Fast Settling, Low Power, Voltage Feedback Amplifie November 1995 National Semiconductor LM6317 120 MHz, Fast Settling, Low Power, **Voltage Feedback Amplifier General Description** Features (Typical unless otherwise noted) Easy to use voltage feedback topology The LM6317 is a high speed, unity-gain stable voltage feedback amplifier that consumes only 40 mW of quiescent pow- Unity-gain stability er. Operating at $\pm 5V$ power supply, the LM6317 provides 120 MHz Wide unity-gain bandwidth excellent AC performance such as 120 MHz of unity-gain 1100V/µs Fast slew rate bandwidth, $1500V/\mu s$ of slew rate, and 80 dB of SFDR. Fast settling time The LM6317 has the slew characteristic of a current feed-- 0.1% 12 ns back amplifier; yet it can be used in all traditional amplifier — 0.01% 18 ns configurations. The high output current and good stability ■ Low SFDR @ 1 MHz Driving 100Ω 80 dB with capacitive load of LM6317 makes it ideal for driving High output current 60 mA cables. With its unity-gain stability, fast settling time and low High CMRR and PSRR 80 dB, 74 dB output impedance, the LM6317 can be used to buffer A/D Low supply current 4 mA converters. The LM6317 also has very low input voltage and ■ Specified for ±5V operation current noise, high CMRR and PSRR, desirable in precision applications such as ATE systems. Applications Active filters A/D Converter buffers Video cable drivers Communication systems Portable systems Ultrasound equipment ATE systems **Typical Performance Connection Diagram** Settling Time vs Gain 8-Pin DIP/SO 160 N/C N/C 140 120 (us) 0.01 100 OUTPUT +INettling Time 80 v-N/C 60 TL/H/12542-2 40 20 **Top View** 0.0 2 3 4 5 6 7 8 9 10 Non-Inverting Gain TL/H/12542-14 **Ordering Information** Temperature Range NSC Transport Package Industrial Media Drawing 40°C to +85°C LM6317IN 8-Pin DIP Rails N08E LM6317IM 8-Pin Small Outline Rails M08A 2.5k Tape and Reel LM6317IMX FinyPak™ is a trademark of National Semiconductor Corp RRD-B30M76/Printed in U. S. A. http://www.national.com © 1996 National Semiconductor Corporation TI /H/12542



Absolute Maximum Ratings (Note 1) If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications. ESD Tolerance (Note 2)

ESD TOIEIAILCE (NOLE 2)	
Human Body Model	1.5 kV
Machine Model	200V
Supply Voltage (V $^+$ –V $^-$)	12V
Differentfial Input Voltage	10V
Output Current (Note 3)	\pm 60 mA
Storage Temperature Range	-65°C to $+150^\circ\text{C}$
Maximum Junction Temperature (Note 4)	150°C

Operating Ratings (Note 1)

Supply Voltage	$\pm 2.3V \leq V_S \leq \pm 6V$
Junction Temperature Range	$-40^{\circ}C \leq T_J \leq +85^{\circ}C$
Thermal Resistance (θ_{JA})	
N Package, 8-Pin Molded DIP	110°C/W
M Package, 8-Pin Surface Mount	170°C/W

\pm 5V DC Electrical Characteristics	Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$,
$V^+ = +5V$, $V^- = -5V$, $V_{CM} = 0V$, and $R_L = 100\Omega$. Bo	bidface limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	Limit (Note 6)	Units
V _{OS}	Input Offset Voltage		0.3	5 7	mV max
TC V_{OS}	Input Offset Voltage Average Drift		8		μV/°C
Ι _Β	Input Bias Current		3	12 22	μA max
I _{OS}	Input Offset Current		0.2	2 4	μA max
R _{IN}	Input Resistance	Differential	2		MΩ
		Common	1		1413.2
C _{IN}	Input Capacitance	Differential	1		pF
		Common	1		P
R _O	Open Loop Output Resistance		0.02		Ω
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 1.5V$	80	62 57	dB min
PSRR	Power Supply Rejection Ratio	$V_{S} = \pm 5V \text{ to } \pm 4.5V$	74	60 52	dB min
A _V	Large Signal Voltage Gain	$V_{OUT} = \pm 1V$ $R_L = 1 k\Omega$	70	55 50	dB
		$V_{OUT} = \pm 1V$ $R_L = 100\Omega$	67	53 48	min
V _{CM}	Input Common-Mode Voltage Range	CMRR = 60 dB	3.2	2.6 2.3	V min
			-3.2	-2.6 - 2.3	V max

Symbol	Parameter	Condi	itions	Typ (Note 5)	Limit (Note 6)	Units
V _O	Output Swing	$R_L = 1$	1 kΩ	3.5	3 2.6	V min
				-3.5	-3 - 2.6	V max
		$R_L = 1$	100Ω	3	2.5 2.3	V min
				-3	-2.5 - 2.3	V max
I _S	Supply Current			4	6 7	mA max
	lectrical Characte e specified, $T_J = 25^{\circ}C$, V ⁺		= 5V, A _V	= 1, and $R_L = 100$	2	
				= 1, and $R_L = 100$ Conditions	2 Typ (Note 5)	Units
nless otherwise	e specified, $T_J = 25^{\circ}C, V^+ =$			Conditions	Тур	Units
nless otherwise Symbol	e specified, T _J = 25°C, V ⁺ = Parameter		5V St	Conditions	Typ (Note 5)	_
nless otherwise Symbol	e specified, T _J = 25°C, V ⁺ = Parameter		5V St 5V St R _L =	Conditions tep tep, $A_V = -1$,	Typ (Note 5) 1100	
nless otherwise Symbol	e specified, T _J = 25°C, V ⁺ = Parameter Slew Rate		5V St 5V St R _L =	Conditions tep tep, $A_V = -1$, 500Ω $a - 1$, $R_L = 500\Omega$	Typ (Note 5) 1100 750	Units V/µs MHz MHz
nless otherwise Symbol	e specified, T _J = 25°C, V ⁺ = Parameter Slew Rate Unity-Gain Bandwidth		5V Si 5V Si RL = A _V =	Conditions tep tep, $A_V = -1$, 500Ω $a - 1$, $R_L = 500\Omega$	Typ (Note 5) 1100 750 120	 MHz
Inless otherwise Symbol SR	e specified, T _J = 25°C, V ⁺ = Parameter Slew Rate Unity-Gain Bandwidth -3 dB Frequency		$5V SI$ $SV SI$ $R_L =$ $A_V =$ $A_V =$	Conditions tep tep, $A_V = -1$, 500Ω $a - 1$, $R_L = 500\Omega$ a + 2	Typ (Note 5) 1100 750 120 80	V/μs MHz MHz
nless otherwise Symbol SR θ _m	e specified, T _J = 25°C, V ⁺ = Parameter Slew Rate Unity-Gain Bandwidth -3 dB Frequency Phase Margin		$5V St$ $5V St$ $R_L =$ $A_V =$ $A_V =$ $A_V =$ 0.1%	Conditions tep tep, $A_V = -1$, 500Ω $a -1$, $R_L = 500\Omega$ a + 2 $a -1$, $R_L = 500\Omega$	Typ (Note 5) 1100 750 120 80 60	 V/μs MHz
Inless otherwise Symbol SR θ _m	e specified, T _J = 25°C, V ⁺ = Parameter Slew Rate Unity-Gain Bandwidth -3 dB Frequency Phase Margin	= +5V, V ⁻	$5V SI$ $5V SI$ $R_L =$ $A_V =$ $A_V =$ 0.1% 0.019	Conditions tep tep, $A_V = -1$, 500Ω $a - 1$, $R_L = 500\Omega$ a + 2 $a - 1$, $R_L = 500\Omega$ a + 2 $a - 1$, $R_L = 500\Omega$	Typ (Note 5) 1100 750 120 80 60 12	V/μs MHz MHz

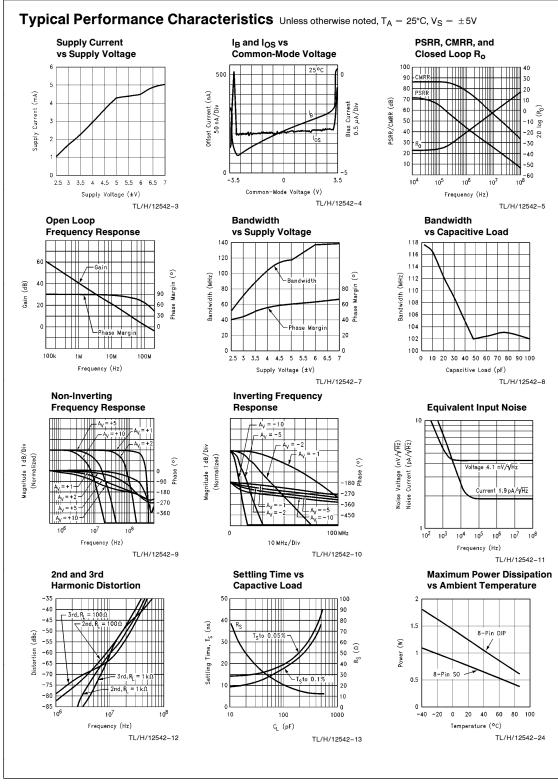
Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics. Note 2: Human body model, 1.5 kΩ in series with 100 pF. Machine model, 200Ω in series with 100 pF.

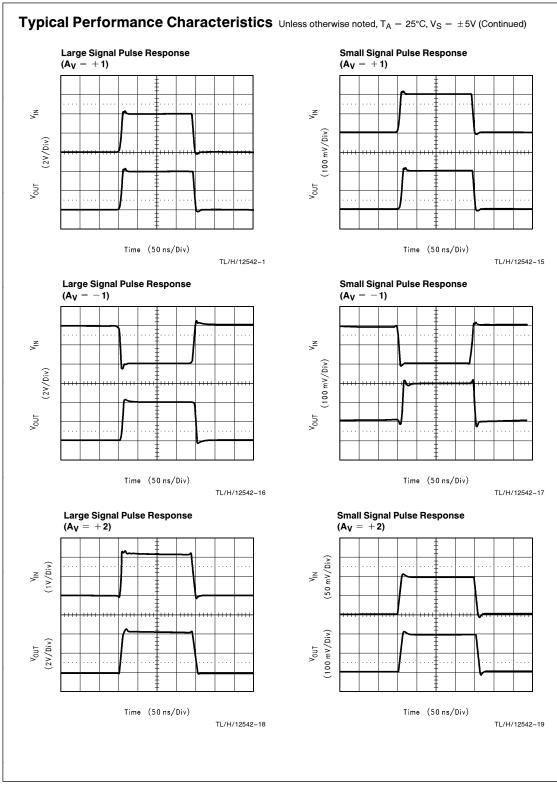
Note 3: Applies to both single-supply and split-supply operation. Sourcing and sinking more than 60 mA at the output may adversely affect reliability.

Note 4: The maximum power dissipation is a function of $T_{J(max)}$, θ_{JA} , and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(max)} - T_A)/\theta_{JA}$. All numbers apply for packages soldered directly into a PC board.

Note 5: Typical values represent the most likely parametric norm.

Note 6: All limits are guaranteed by testing or statistical analysis.





Application Notes

Using the LM6317

LIMITS AND PRECAUTIONS

The absolute maximum supply voltage which may be applied to the LM6317 is 12V. Designers should not design for more than 10V nominal, and carefully check supply tolerances under all conditions so that the voltages do not exceed the maximum.

DIFFERENTIAL INPUT VOLTAGE

Differential input voltage is the difference in voltage between the non-inverting (+) input and the inverting (-) input of the op amp. The absolute maximum differential input for the LM6317 is 10V across the inputs. This limit also applies when there is no power supplied to the op amp. This may not be a problem in most conventional op amp designs, however, designers should avoid using the LM6317 as comparators or forcing the inputs to different voltages. In some designs, diodes protection may be needed between the inputs, as shown in *Figure 1*.

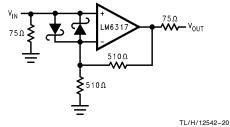


FIGURE 1. Input Protection for LM6317

Layout Consideration

PRINTED CIRCUIT BOARDS AND HIGH SPEED OP AMPS

There are many things to consider when designing PC boards for high speed op amps. Without proper caution, it is very easy and frustrating to have excessive ringing, oscillation and other degraded AC performance in high speed circuits. As a rule, the signal traces should be short and wide to provide low inductance and low impedance paths. Any unused board space needs be grounded to reduce stray signal pickup. Critical components should also be grounded at a common point to eliminate voltage drop. Sockets add capacitance to the board and can affect frequency performance. It is better to solder the amplifier directly into the PC board without using any socket.

USING PROBES

Active (FET) probes are ideal for taking high frequency measurements because they have wide bandwidth, high input impedance and low input capacitance. However, the probe ground leads provide a long ground loop that will produce errors in measurement. Instead, the probes can be grounded directly by removing the ground leads and probe jackets and using scope probe jacks.

COMPONENTS SELECTION AND FEEDBACK RESISTOR

It is important in high speed applications to keep all component leads short because wires are inductive at high frequency. For discrete components, choose carbon composition-type resistors and mica-type capacitors. Surface mount components are preferred over decrete components for minimum inductive effect.

Large values of feedback resistors can couple with parasitic capacitance and cause undersirable effects such as ringing or oscillation in high speed amplifiers. Feedback resistor value around 1 k Ω is recommended.

COMPENSATION FOR INPUT CAPACITANCE

The combination of an amplifier's input capacitance with the gain setting resistors adds a pole that can cause peaking or oscillation. To solve this problem, a feedback capacitor with a value

$c_{\text{F}} > (\text{R}_{\text{G}} \times c_{\text{IN}})/\text{R}_{\text{F}}$

can be used to cancel that pole. The value of $C_{\rm IN}$ can be found in the DC Electrical Characteristics Table of the datasheet. *Figure 2* illustrates the compensation circuit.

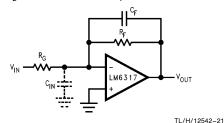
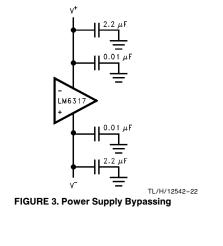


FIGURE 2. Compensating for Input Capacitance

Power Supply Bypassing

Bypassing the power supply is necessary to maintain low power supply impedance across frequency. Both positive and negative power supplies should be bypassed individually by placing 0.01 μ F creramic capacitors directly to power supply pins and 2.2 μ F tantalum capacitors close to the power supply pins.



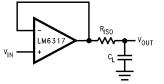
Application Notes (Continued)

Termination

In high frequency applications, reflections occur if signals are not properly terminated. To minimize reflection, coaxial cable with matching characteristic impedance to the signal source should be used. The other end of the cable should be terminated with the same value terminator or resistor. For the commonly used cables. RG59 has 75Ω characteristics impedance, and RG58 has 50Ω characteristics impedance.

Driving Capacitive Loads

Amplifiers driving capacitive loads can oscillate or have ringing at the output. To eliminate oscillation or reduce ringing, an isolation resistor can be placed as shown below in *Figure 4*. The combination of the isolation resistor and the load capacitor froms a pole to incease stability by adding more phase margin to the overall system. The desired performance depends on the value of the isolation resistor; the bigger the isolation resistor, the more damped the pulse response becomes. A 50 Ω isolation resistor is recommended for initial evaluation.



TL/H/12542-23

FIGURE 4. Driving Capacitive Load

Physical Dimensions inches (millimeters) unless otherwise noted

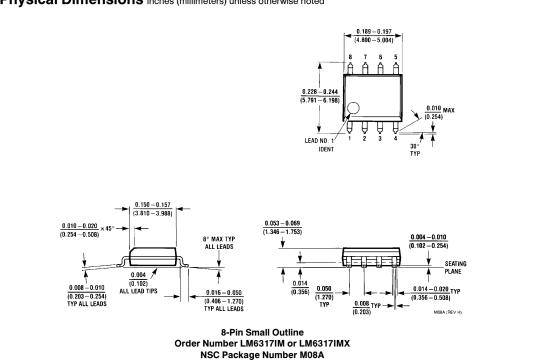
Other High Speed and Video Amplifiers

National Semiconductor has an extensive line of high speed amplifiers, with a range of operating voltage from 3V single supply to \pm 15V, and a range of package types, such as the space saving SOT23-5 TinyPakTM (3.05mm \times 3.00mm \times 1.43mm - about the size of a grain of rice) and a wide SO-8 for better power dissipation.

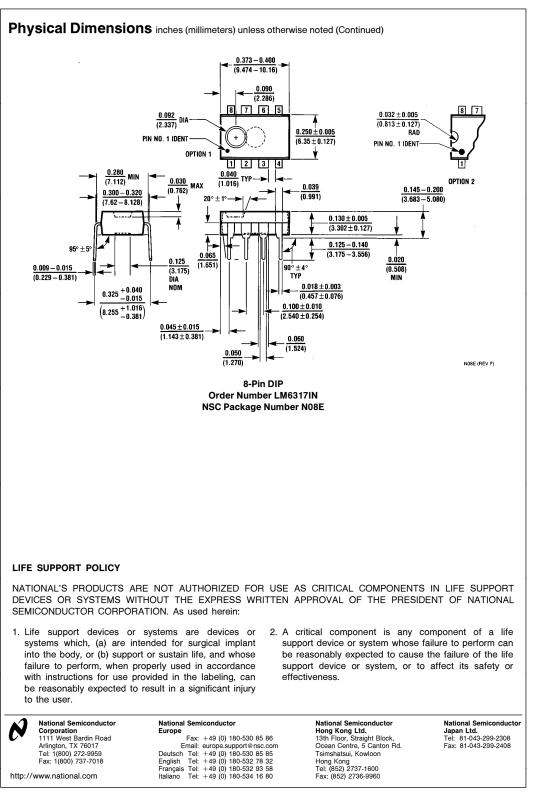
This op amp line includes -

- LM6171 100 MHz low distortion amplifier with greater than 3000V/ μ s slew rate. Voltage feedback design draws only 2.5 mA. Specified at \pm 15V and \pm 5V supplies.
- LM7131 TinyPak (SOT23-5) video amplifier with 70 MHz gain bandwidth. Specified at 3V, 5V and \pm 5V supplies.
- LM7171 200 MHz voltage feedback amplifier with 100 mA output current and 4000V/µs slew rate. Supply current of 6.5 mA. Specified at ±15V and ±5V supplies.

Information on these parts is available from your National Semiconductor representative.



LM6317 120 MHz, Fast Settling, Low Power, Voltage Feedback Amplifier



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